

# 3A, 50V - 1000V Surface Mount Fast Recovery Rectifier

## FEATURES

- Glass passivated chip junction
- Ideal for automated placement
- Fast switching for high efficiency
- High surge current capability
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

## **APPLICATIONS**

- Switching mode power supply (SMPS)
- Adapters
- Lighting application
- Converter

## **MECHANICAL DATA**

- Case: DO-214AB (SMC)
- Molding compound meets UL 94V-0 flammability rating
- Part no. with suffix "H" means AEC-Q101 qualified
- Packing code with suffix "G" means green compound (halogen-free)
- Moisture sensitivity level: level 1, per J-STD-020
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 0.21 g (approximately)

KEY PARAMETERS					
PARAMETER	VALUE	UNIT			
I <sub>F(AV)</sub>	3	А			
V <sub>RRM</sub>	50 - 1000	V			
I <sub>FSM</sub>	100	А			
T <sub>J MAX</sub>	150	°C			
Package	DO-214AB	(SMC)			
Configuration	Single	die			





DO-214AB (SMC)

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)									
PARAMETER	SYMBOL	RS3A	RS3B	RS3D	RS3G	RS3J	RS3K	RS3M	UNIT
Marking code on the device		RS3A	RS3B	RS3D	RS3G	RS3J	RS3K	RS3M	
Repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V
Reverse voltage, total rms value	V <sub>R(RMS)</sub>	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	V
Forward current	I <sub>F(AV)</sub>				3				А
Surge peak forward current, 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>				100				A
Junction temperature	TJ			- {	55 to +1	50			°C
Storage temperature	T <sub>STG</sub>			- {	55 to +1	50			°C



THERMAL PERFORMANCE						
PARAMETER	SYMBOL	LIMIT	UNIT			
Junction-to-lead thermal resistance per diode	R <sub>ejl</sub>	15	°C/W			
Junction-to-ambient thermal resistance per diode	R <sub>eja</sub>	50	°C/W			

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_A = 25^{\circ}C$ unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	TYP.	MAX.	UNIT
Forward voltage per diode $^{(1)}$		$I_F = 3A, T_J = 25^{\circ}C$	V <sub>F</sub>	-	1.3	V
Deverse surrent @ reted \/ r	a and $a$ $(2)$	$T_J = 25^{\circ}C$		-	10	μA
Reverse current @ rated $V_R$ per diode <sup>(2)</sup>		T <sub>J</sub> = 125°C	I <sub>R</sub>	-	250	μA
Reverse recovery time	RS3A RS3B RS3D RS3G	I <sub>F</sub> =0.5A , I <sub>R</sub> =1.0A	t <sub>rr</sub>	-	150	ns
	RS3J	I <sub>RR</sub> =0.25A	٩rr	-	250	ns
	RS3K RS3M			-	500	ns

#### Notes:

1. Pulse test with PW=0.3 ms

2. Pulse test with PW=30 ms



ORDERING INFORMATION						
PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX	PACKAGE	PACKING	
		R7		SMC	850 / 7" Plastic reel	
		R6		SMC	3,000 / 13" Paper reel	
RS3x (Note 1)	Н	M6	G	SMC	3,000 / 13" Plastic reel	
		V7		Matrix SMC	850 / 7" Plastic reel	
		V6		Matrix SMC	3,000 / 13" Plastic reel	

#### Note :

1. "x" defines voltage from 50V (RS3A) to 1000V (RS3M)

EXAMPLE						
EXAMPLE P/N	PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION	
RS3AHR7G	RS3A	Н	R7	G	AEC-Q101 qualified Green compound	



## **CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25°C unless otherwise noted)

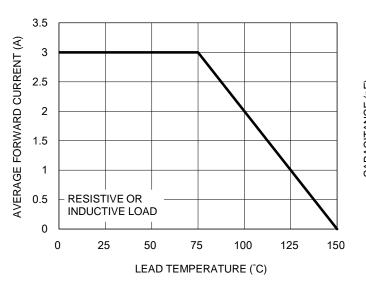
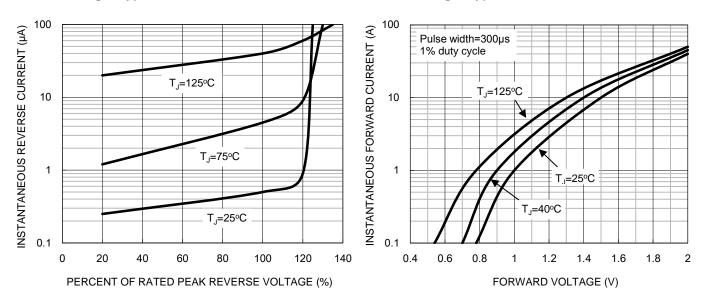


Fig.1 Forward Current Derating Curve

#### Fig.2 Typical Junction Capacitance

#### Fig.3 Typical Reverse Characteristics







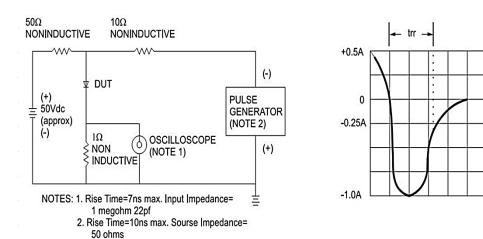
## **CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25°C unless otherwise noted)

#### Fig.5 Maximum Non-repetitive Forward Surge Current



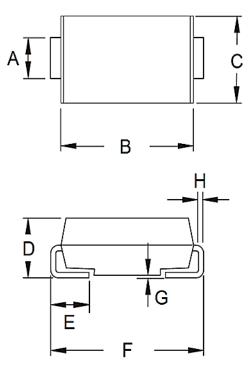
#### Fig.6 Reverse Recovery Time Characteristic And Test Circuit Diagram





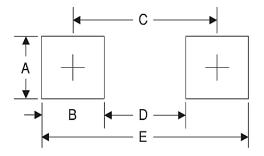
## **PACKAGE OUTLINE DIMENSIONS**

DO-214AB (SMC)



	DIM. Unit (mm)		Unit	(inch)
DIN.	Min.	Max.	Min.	Max.
А	2.90	3.20	0.114	0.126
В	6.60	7.11	0.260	0.280
С	5.59	6.22	0.220	0.245
D	2.00	2.62	0.079	0.103
E	1.00	1.60	0.039	0.063
F	7.75	8.13	0.305	0.320
G	0.10	0.20	0.004	0.008
Н	0.15	0.31	0.006	0.012

# SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
А	3.30	0.130
В	2.50	0.098
С	6.80	0.268
D	4.40	0.173
E	9.40	0.370

#### **MARKING DIAGRAM**



- P/N =Marking Code
- G =Green Compound
- YW =Date Code
- F =Factory Code



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